

EM27C256 256K (32K x 8) UVPROM

Features

- **Functional Compatible to AMD's AM27C256**
- **Fast Read Access Time – 45 ns**
- **Low-Power CMOS Operation**
 - 100 μ A Max Standby
 - 20 mA Max Active at 5 MHz
- **JEDEC Standard Packages – 28-lead ceramic DIP**
- **5V \pm 10% Supply**
- **High-Reliability CMOS Technology**
 - 2,000V ESD Protection
 - 200 mA Latchup Immunity
- **Rapid Programming Algorithm – 100 μ s/Byte (Typical)**
- **CMOS and TTL Compatible Inputs and Outputs**
- **Integrated Product Identification Code**
- **Industrial, Extended Temperature Ranges and Military Screening**

1. Description

The EM27C256 is fabricated using high-density nonvolatile memory CMOS process and is assembled and tested in EM Semi approved assembly and test facilities. The device is offered in industrial, extended and a version screened to a military test flow.

The EM27C256 is a low-power, high-performance 262,144-bit UVPROM organized 32K by 8 bits. It requires only one 5V power supply in normal read mode operation. Any byte can be accessed in less than 45 ns, eliminating the need for speed reducing WAIT states on high-performance microprocessor systems.

Atmel's scaled CMOS technology provides high-speed, lower active power consumption, and significantly faster programming. Power consumption is typically only 8 mA in Active Mode and less than 10 μ A in Standby.

The EM27C256 is available in industry-standard JEDEC-approved ceramic DIP packages. All devices feature two-line control (CE_{NOT} , OE_{NOT}) to give designers the flexibility to prevent bus contention.

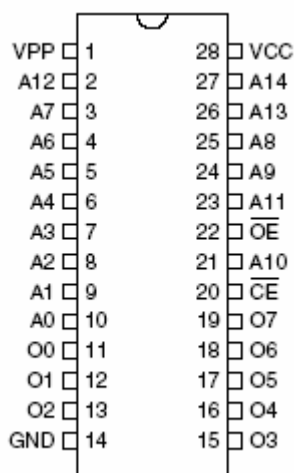
With 32K byte storage capability, the EM27C256 allows firmware to be stored reliably and to be accessed by the system without the delays of mass storage media.

EM27C256 has additional features to ensure high quality and efficient production use. The Rapid Programming Algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 100 μ s/byte. The Integrated Product Identification Code electronically identifies the device and manufacturer. This feature is used by industry-standard programming equipment to select the proper programming algorithms and voltages.

2. Pin Configurations

| Pin Name | Function |
|-------------------|---------------|
| A0 – A14 | Addresses |
| O0 - O7 | Outputs |
| CE _{NOT} | Chip Enable |
| OE _{NOT} | Output Enable |
| NC | No Connect |

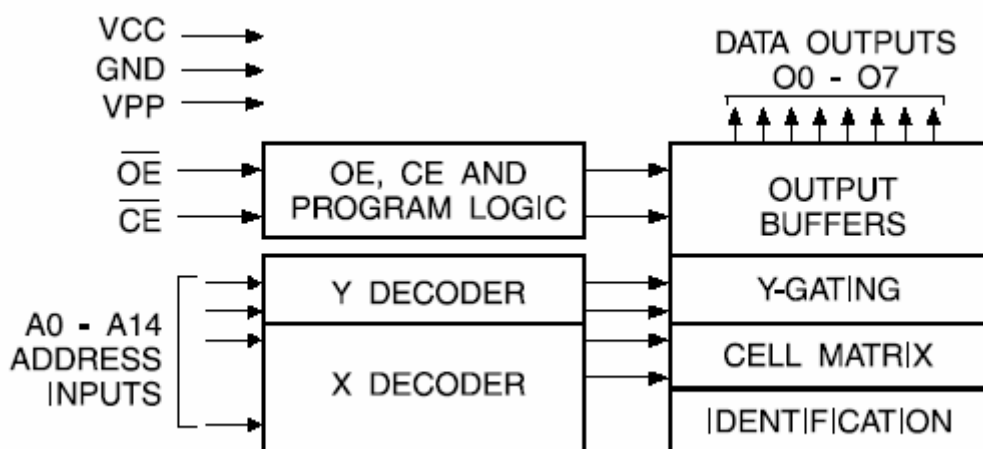
2.1 28-lead Ceramic DIP Top View



3. System Considerations

Switching between active and standby conditions via the Chip Enable pin may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed datasheet limits, resulting in device non-conformance. At a minimum, a 0.1 μF high frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the Vcc and Ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a 4.7 μF bulk electrolytic capacitor should be utilized, again connected between the Vcc and Ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.

4. Block Diagram



5. Absolute Maximum Ratings*

| | |
|--|---------------------------------|
| Temperature Under Bias..... | -55°C to + 125°C |
| Storage Temperature | -65°C to + 150°C |
| Voltage on Any Pin with Respect to Ground | -2.0V to + 7.0V ⁽¹⁾ |
| Voltage on A9 with Respect to Ground | -2.0V to + 14.0V ⁽¹⁾ |
| V _{PP} Supply Voltage with Respect to Ground | -2.0V to + 14.0V ⁽¹⁾ |

* NOTICE:

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note:

1. Minimum voltage is -0.6V DC which may undershoot to -2.0V for pulses of less than 20 ns. Maximum output pin voltage is V_{CC} + 0.75V DC which may overshoot to +7.0 volts for pulses of less than 20 ns.

6. Operating Modes

| Mode/Pin | CE _{NOT} | OE _{NOT} | A _i | V _{PP} | Outputs |
|---------------------------------------|-------------------|-------------------|---|-----------------|---------------------|
| Read | V _{IL} | V _{IL} | A _i | V _{CC} | D _{OUT} |
| Output Disable | V _{IL} | V _{IH} | X ⁽¹⁾ | V _{CC} | High Z |
| Standby | V _{IH} | X ⁽¹⁾ | X ⁽¹⁾ | V _{CC} | High Z |
| Rapid Program ⁽²⁾ | V _{IL} | V _{IH} | A _i | V _{PP} | D _{IN} |
| PGM Verify ⁽²⁾ | X ⁽¹⁾ | V _{IL} | A _i | V _{PP} | D _{OUT} |
| Optional PGM Verify ⁽²⁾ | V _{IL} | V _{IL} | A _i | V _{CC} | D _{OUT} |
| PGM Inhibit ⁽²⁾ | V _{IH} | V _{IH} | X ⁽¹⁾ | V _{PP} | High Z |
| Product Identification ⁽⁴⁾ | V _{IL} | V _{IL} | A ₉ = V _H ⁽³⁾ A ₀ = V _{IH} or V _{IL} A ₁ - A ₁₄ = V _{IL} | V _{CC} | Identification Code |

Notes:

1. X can be V_{IL} or V_{IH} .
2. Refer to Programming Characteristics.
3. $V_H = 12.0 \pm 0.5V$.
4. Two identifier bytes may be selected. All A_i inputs are held low (V_{IL}), except A_9 which is set to V_H and A_0 which is toggled low (V_{IL}) to select the Manufacturer's Identification byte and high (V_{IH}) to select the Device Code byte.

7. DC and AC Operating Conditions for Read Operation

| | | EM27C256 | |
|------------------------|------------|---------------|---------------|
| | | -45 | -70 / -90 |
| Operating Temp.(Case) | Industrial | -40°C - 85°C | -40°C - 85°C |
| | Extended | -45°C - 115°C | -45°C - 115°C |
| | Military | -55°C - 125°C | -55°C - 125°C |
| V _{CC} Supply | | 5V ± 10% | 5V ± 10% |

8. DC and Operating Characteristics for Read Operation

| Symbol | Parameter | Condition | Min | Max | Units | |
|---------------------|---|---|-------------|-----------------------|-------|----|
| I _{LI} | Input Load Current | V _{IN} = 0V to V _{CC} | Ind. | | ±1 | μA |
| | | | Ext. / Mil. | | ±5 | μA |
| I _{LO} | Output Leakage Current | V _{OUT} = 0V to V _{CC} | Ind. | | ±5 | μA |
| | | | Ext. / Mil. | | ±10 | μA |
| I _{PP1(2)} | V _{PP(1)} Read/Standby Current | V _{pp} = V _{CC} | | 10 | μA | |
| I _{SB} | V _{CC(1)} Standby Current | I _{SB1} (CMOS), C _{E_{NOT}} = V _{CC} ± 0.3V | | 100 | μA | |
| | | I _{SB2} (TTL), C _{E_{NOT}} = 2.0 to V _{CC} +0.5V | | 1 | mA | |
| I _{CC} | V _{CC} Active Current | f = 5 MHz, I _{OUT} = 0 mA, C _{E_{NOT}} = V _{IL} | | 20 | mA | |
| V _{IL} | Input Low Voltage | | -0.6 | 0.8 | V | |
| V _{IH} | Input High Voltage | | 2.0 | V _{CC} + 0.5 | V | |
| V _{OL} | Output Low Voltage | I _{OL} = 2.1 mA | | 0.4 | V | |
| V _{OH} | Output High Voltage | I _{OH} = -400 μA | 2.4 | | V | |

Note:

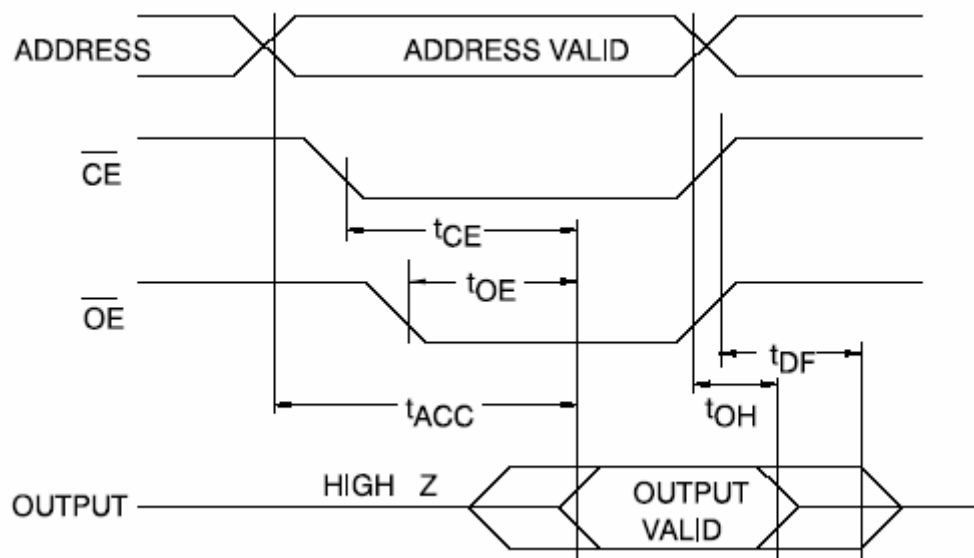
1. V_{CC} must be applied simultaneously with or before V_{PP}, and removed simultaneously with or after V_{PP}.
2. V_{pp} may be connected directly to V_{CC}, except during programming. The supply current would then be the sum of I_{CC} and I_{pp}.

9. AC Characteristics for Read Operation

| Symbol | Parameter | Condition | EM27C256 | | | | Units |
|--------------|---|--------------------------------|----------|-----|-----------|-----|-------|
| | | | -45 | | -70 / -90 | | |
| | | | Min | Max | Min | Max | |
| $t_{ACC(1)}$ | Address to Output Delay | $CE_{NOT} = OE_{NOT} = V_{IL}$ | | 45 | | 70 | ns |
| $t_{CE(1)}$ | CE_{NOT} to Output Delay | $OE_{NOT} = V_{IL}$ | | 45 | | 70 | ns |
| $t_{OE(1)}$ | OE_{NOT} to Output Delay | $CE_{NOT} = V_{IL}$ | | 20 | | 30 | ns |
| $t_{DF(1)}$ | OE_{NOT} or CE_{NOT} High to Output Float, Whichever Occurred First | | | 20 | | 25 | ns |
| t_{OH} | Output Hold from Address, CE_{NOT} or OE_{NOT} , Whichever Occurred First | | 7 | | 7 | | ns |

Note: 1. See AC Waveforms for Read Operation.

10. AC Waveforms for Read Operation⁽¹⁾

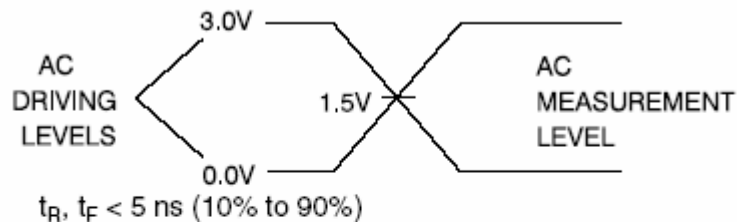


Notes:

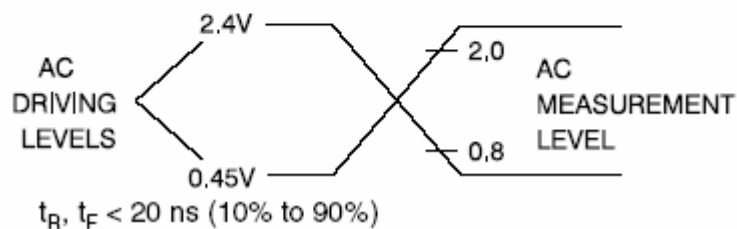
1. Timing measurement reference level is 1.5V for -45 devices. Input AC drive levels are $V_{IL} = 0.0V$ and $V_{IH} = 3.0V$. Timing measurement reference levels for all other speed grades are $V_{OL} = 0.8V$ and $V_{OH} = 2.0V$. Input AC drive levels are $V_{IL} = 0.45V$ and $V_{IH} = 2.4V$.
2. OE_{NOT} may be delayed up to $t_{CE} - t_{OE}$ after the falling edge of CE_{NOT} without impact on t_{CE} .
3. OE_{NOT} may be delayed up to $t_{ACC} - t_{OE}$ after the address is valid without impact on t_{ACC} .
4. This parameter is only sampled and is not 100% tested.
5. Output float is defined as the point when data is no longer driven.

11. Input Test Waveforms and Measurement Levels

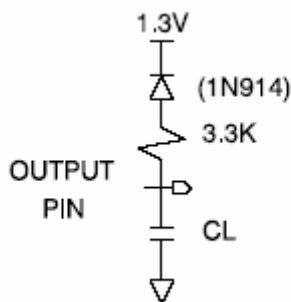
For -45 devices only:



For -70 devices:



12. Output Test Load



Note:

1. $C_L = 100 \text{ pF}$ including jig capacitance, except for the -45 devices, where $C_L = 30 \text{ pF}$.

13. Pin Capacitance

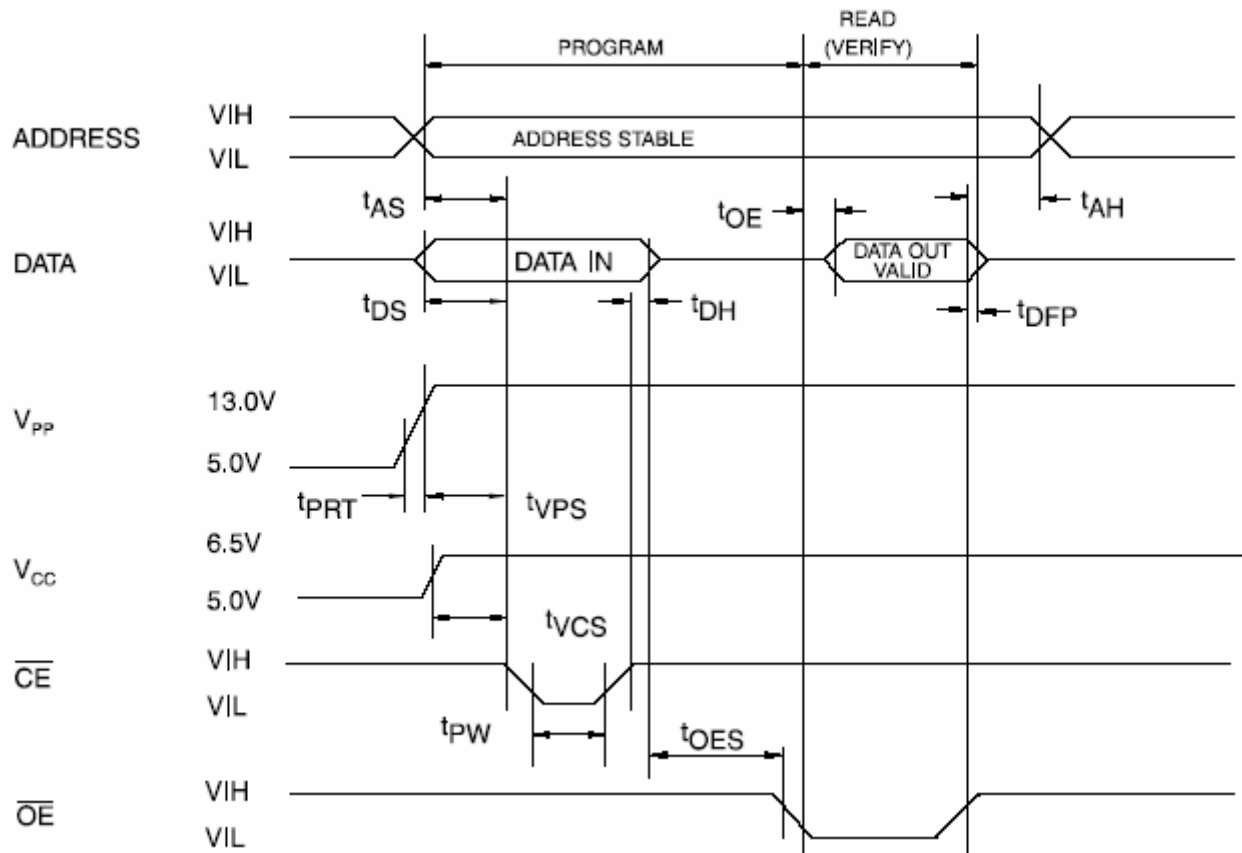
$f = 1 \text{ MHz}$, $T = 25^\circ\text{C}$ (1)

| Symbol | Typ | Max | Units | Conditions |
|-----------|-----|-----|-------|----------------|
| C_{IN} | 4 | 6 | pF | $V_{IN} = 0V$ |
| C_{OUT} | 8 | 12 | pF | $V_{OUT} = 0V$ |

Note:

1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested.

14. Programming Waveforms(1)



Notes:

1. The Input Timing Reference is 0.8V for V_{IL} and 2.0V for V_{IH} .
2. t_{OE} and t_{DFP} are characteristics of the device but must be accommodated by the programmer.
3. When programming the EM27C256 a 0.1 μ F capacitor is required across V_{pp} and ground to suppress spurious voltage transients.

15. DC Programming Characteristics

$T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.5 \pm 0.25\text{V}$, $V_{PP} = 13.0 \pm 0.25\text{V}$

| Symbol | Parameter | Test Conditions | Limits | | Units |
|-----------|--|-----------------------------|--------|--------------|---------------|
| | | | Min | Max | |
| I_{LI} | Input Load Current | $V_{IN} = V_{IL}, V_{IH}$ | | ± 10 | μA |
| V_{IL} | Input Low Level | | -0.6 | 0.8 | V |
| V_{IH} | Input High Level | | 2.0 | $V_{CC} + 1$ | V |
| V_{OL} | Output Low Voltage | $I_{OL} = 2.1 \text{ mA}$ | | 0.4 | V |
| V_{OH} | Output High Voltage | $I_{OH} = -400 \mu\text{A}$ | 2.4 | | V |
| I_{CC2} | V_{CC} Supply Current (Program and Verify) | | | 25 | mA |
| I_{PP2} | V_{PP} Current | $CE_{NOT} = V_{IL}$ | | 25 | mA |
| V_{ID} | A9 Product Identification Voltage | | 11.5 | 12.5 | V |

16. AC Programming Characteristics

$T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.5 \pm 0.25\text{V}$, $V_{PP} = 13.0 \pm 0.25\text{V}$

| Symbol | Parameter | Test Conditions ⁽¹⁾ | Limits | | Units |
|-----------|--|---|--------|-----|---------------|
| | | | Min | Max | |
| t_{AS} | Address Setup Tim | Input Rise and Fall Times (10% to 90%) 20 ns | 2 | | μs |
| t_{OES} | OE_{NOT} Setup Time | | 2 | | μs |
| t_{DS} | Data Setup Time | | 2 | | μs |
| t_{AH} | Address Hold Time | Input Pulse Levels | 0 | | μs |
| t_{DH} | Data Hold Time | 0.45V to 2.4V | 2 | | μs |
| t_{DFP} | OE_{NOT} High to Output Float Delay ⁽²⁾ | Input Timing Reference Level | 0 | 130 | ns |
| t_{VPS} | V_{PP} Setup Time | 0.8V to 2.0V | 2 | | μs |
| t_{VCS} | Vcc Setup Time | | 2 | | μs |
| t_{PW} | CE_{NOT} Program Pulse Width ⁽³⁾ | Output Timing Reference Level | 95 | 105 | μs |
| t_{OE} | Data Valid from OE_{NOT} ⁽²⁾ | 0.8V to 2.0V | | 150 | ns |
| t_{PRT} | V_{PP} Pulse Rise Time During Programming | | 50 | | ns |

Notes:

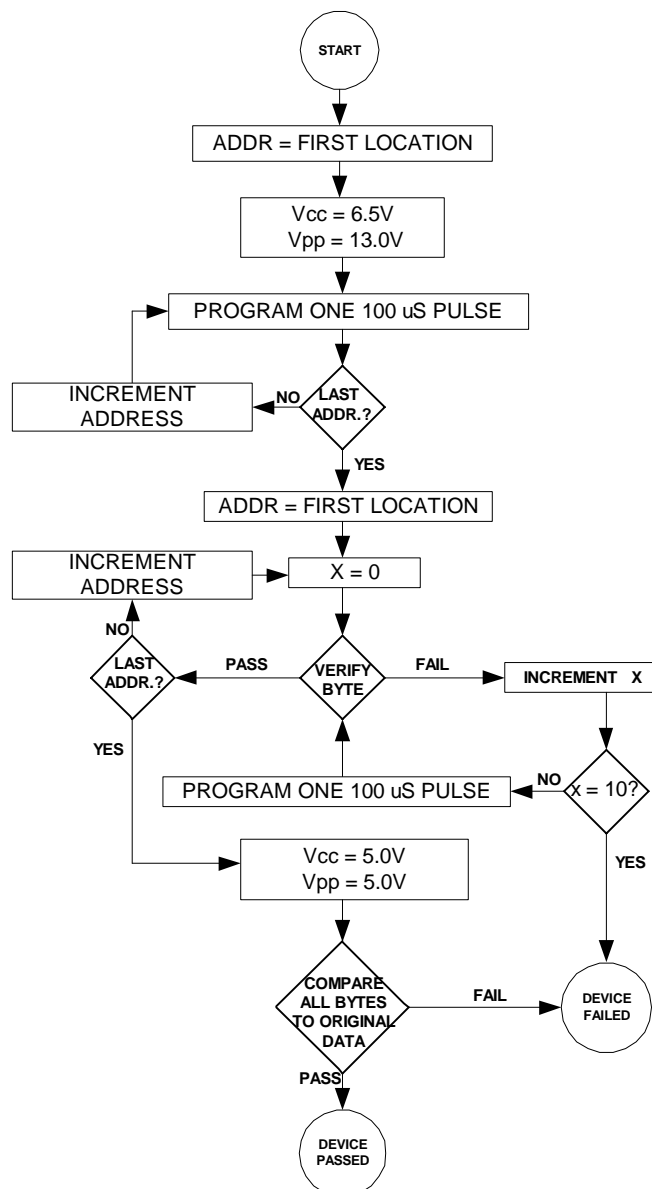
- V_{CC} must be applied simultaneously or before V_{PP} and removed simultaneously or after V_{PP} .
- This parameter is only sampled and is not 100% tested. Output Float is defined as the point where data is no longer driven – see timing diagram.
- Program Pulse width tolerance is $100 \mu\text{sec} \pm 5\%$.

17. EM27C256 Integrated Product Identification Code

| Codes | Pins | | | | | | | | | Hex Data |
|--------------|------|----|----|----|----|----|----|----|----|----------|
| | A0 | O7 | O6 | O5 | O4 | O3 | O2 | O1 | O0 | |
| Manufacturer | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1E |
| Device Type | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 8C |

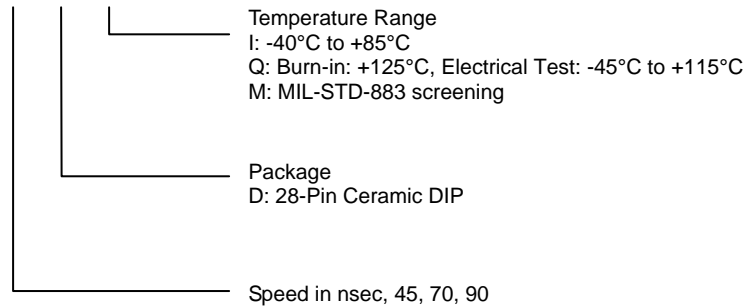
18. Rapid Programming Algorithm

A 100 μs CE_{NOT} pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5V and V_{PP} is raised to 13.0V. Each address is first programmed with one 100 μs CE_{NOT} pulse without verification. Then a verification/reprogramming loop is executed for each address. In the event a byte fails to pass verification, up to 10 successive 100 μs pulses are applied with a verification after each pulse. If the byte fails to verify after 10 pulses have been applied, the part is considered failed. After the byte verifies properly, the next address is selected until all have been checked. V_{PP} is then lowered to V_{IL} and V_{CC} to 5.0V. All bytes are read again and compared with the original data to determine if the device passes or fails.



19. Ordering Information

EM27C256 – XX X X



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